

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Max Tc = +25°C
60V	19mΩ @ V <sub>GS</sub> = 10V	33.2A
000	28mΩ @ V <sub>GS</sub> = 4.5V	28A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Engine-management systems
- Body control electronics
- **DC-DC** converters

Site 1:

### **Features and Benefits**

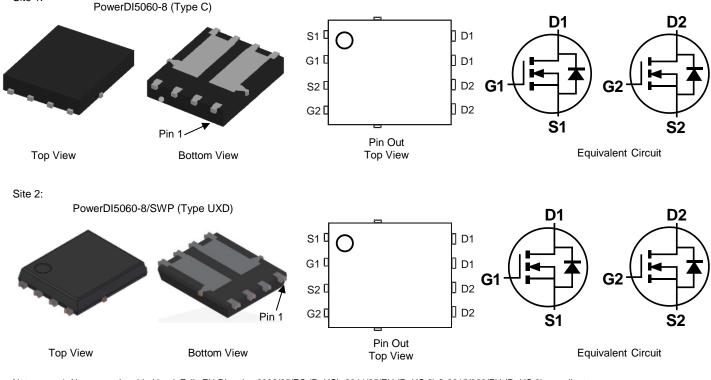
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

An automotive-compliant part is available under separate datasheet (DMTH6016LPDQ)

## Mechanical Data

- Package: PowerDI®5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
  - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

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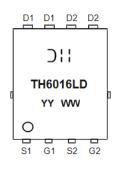


### Ordering Information (Note 4)

Part Number	Backage	Packing		
	Package	Qty.	Carrier	
DMTH6016LPD-13	PowerDI5060-8 (Type C)	2,500	Tape & Reel	
	PowerDI5060-8/SWP (Type UXD)	2,500	Tape & Reel	

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



Characteria Contractor Contra TH6016LD = Product Type Marking Code YYWW = Date Code Marking YY or  $\overline{YY}$  = Year (ex: 23 = 2023) WW = Week (01 to 53)

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	60	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current (Note 5)	Tc = +25°C T <sub>C</sub> = +100°C	ID	33.2 23.7	A
Continuous Drain Current (Note 6)	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	lD	9.2 6.5	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	50	A	
Maximum Continuous Body Diode Forward Current (Note 5)	ls	31	А	
Avalanche Current, L = 0.1mH	las	15.3	А	
Avalanche Energy, L = 0.1mH	E <sub>AS</sub>	11.7	mJ	

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6) T <sub>A</sub> = +25°C		PD	2.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	58	°C/W	
Total Power Dissipation (Note 5) T <sub>C</sub> = +25°C		PD	37.5	W
Thermal Resistance, Junction to Case (Note 5)	Rejc	4	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	٥C	

Notes:

Thermal resistance from junction to soldering point (on the exposed drain pad).
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



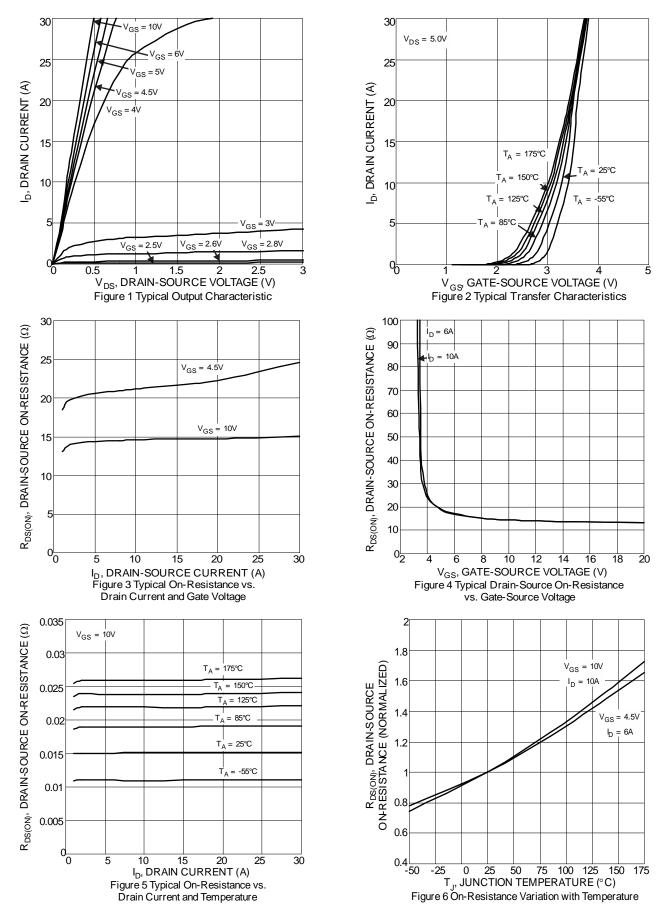
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)					•		
Drain-Source Breakdown Voltage	BVDSS	60	—	_	V	Vgs = 0V, Id = 250µA	
Zero Gate Voltage Drain Current	IDSS		—	1	μA	V <sub>DS</sub> = 48V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	Igss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(th)	1	_	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Proven	_	14.5	19	mΩ	$V_{GS} = 10V, I_D = 10A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		20.9	28	11152	$V_{GS} = 4.5V, I_D = 6A$	
Diode Forward Voltage	Vsd		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	864	_	pF		
Output Capacitance	Coss		282	_	pF	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V f = 1MHz	
Reverse Transfer Capacitance	Crss		27	—	pF		
Gate Resistance	Rg	_	1.3	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		8.4	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		17	_	nC		
Gate-Source Charge	Qgs		3.1	_	nC	V <sub>DS</sub> = 30V, I <sub>D</sub> = 10A	
Gate-Drain Charge	Q <sub>gd</sub>		4.3	—	nC		
Turn-On Delay Time	td(ON)	_	3.4	—	ns		
Turn-On Rise Time	tR		5.2	_	ns	$V_{DD} = 30V, V_{GS} = 10V$ $I_D = 10A, R_g = 6\Omega$	
Turn-Off Delay Time	tD(OFF)		13	—	ns		
Turn-Off Fall Time	t <sub>F</sub>		7	_	ns		
Body Diode Reverse Recovery Time	trr		22	_	ns		
Body Diode Reverse Recovery Charge	Qrr	_	11	_	nC	I⊧ = 10A, dl/dt = 100A/µs	

Notes: 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.

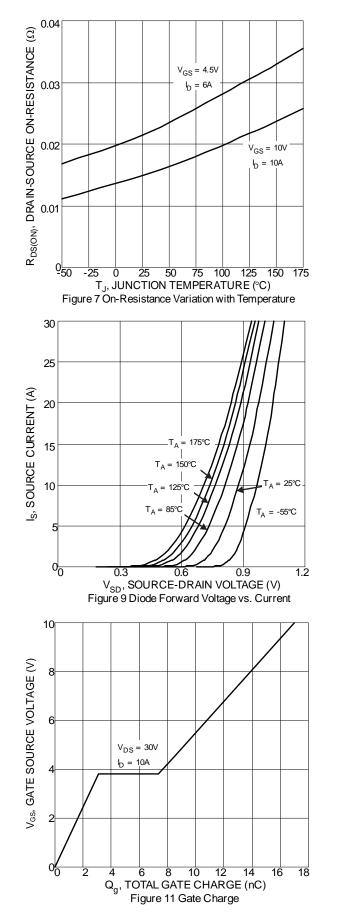


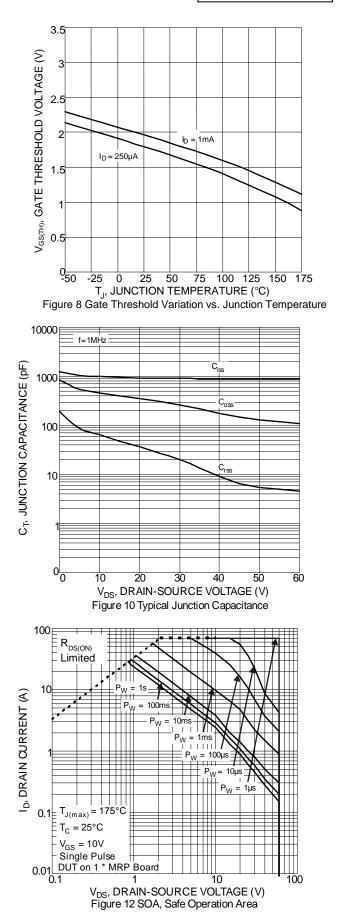
## DMTH6016LPD



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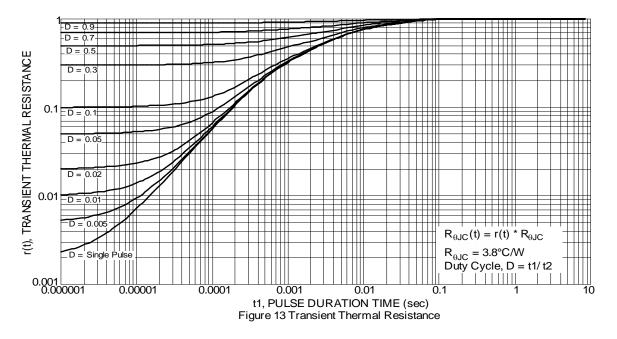






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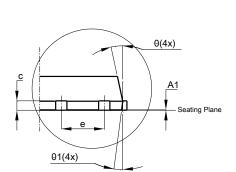


## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

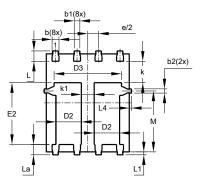
Site 1:

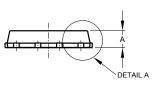
D D1 E1 Ø1.000 Depth 0.07±0.030



PowerDI5060-8 (Type C)

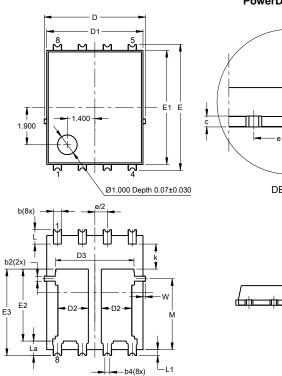
DETAIL A





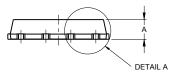
Pow	PowerDI5060-8 (Type C)				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05	0.02		
b	0.33	0.51	0.41		
b1	0.300	0.366	0.333		
b2	0.20	0.35	0.25		
С	0.23	0.33	0.277		
D	5	.15 BS0	0		
D1	4.85	4.95	4.90		
D2	1.40	1.60	1.50		
D3	-	-	3.98		
Е	6	.15 BS0	0		
E1	5.75	5.85	5.80		
E2	3.56	3.76	3.66		
е	1	.27BSC			
k	-	-	1.27		
k1	0.56	-	-		
L	0.51	0.71	0.61		
La	0.51	0.71	0.61		
L1	0.05	0.20	0.175		
L4	-	-	0.125		
М	3.50	3.71	3.605		
х	-	-	1.400		
у	-	-	1.900		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	All Dimensions in mm				

Site 2:



PowerDI5060-8/SWP (Type UXD)

A1 Seating Plane	
DETAIL A	



PowerDI5060-8/SWP (Type UXD)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0.00	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	(	).25REF	-	
С	0.230	0.330	0.277	
D	5	.15 BS0	2	
D1	4.70	5.10	4.90	
D2	1.46	1.66	1.55	
D3	3.78	4.18	3.98	
Е	6	6.40 BS0	2	
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1	1.27BSC	)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
М	3.205	4.005	3.605	
W	0.025	0.225	0.125	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				

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## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

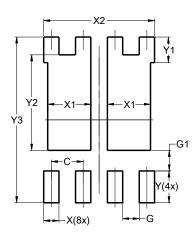
X4 Y2 Y2 Y3 Y2 Y3 Y4 Y2 Y1 Y2 Y1 Y4 Y(4x) Y(4x)Y

Dimensions	Value		
	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	3.910		
X2	1.650		
X3	1.650		
X4	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		

Site 2:

### PowerDI5060-8/SWP (Type UXD)

PowerDI5060-8 (Type C)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	1.720
X2	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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